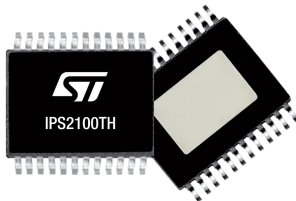


## Dual channel high-side switch with current sense



Product status link

[IPS2100TH](#)

Product label



### Features

- $R_{ON(Typ.)} (@T_J = 25\text{ }^{\circ}\text{C}) = 50\text{ m}\Omega$
- Very low standby current
- 3.3 V CMOS compatible inputs
- Optimized electromagnetic emission
- Very low electromagnetic susceptibility
- Proportional load current sense
- Very low current sense leakage
- High current sense precision for wide range currents
- Off-state open-load detection
- Output short to VCC detection
- Overload and short to ground latch-off
- Thermal shutdown latch-off
- Undervoltage shutdown
- Overvoltage clamp
- Load current limitation
- Fault reset standby pin (FR\_STBY)
- Self limiting of fast thermal transients
- Protection against loss of ground and loss of VCC
- Designed to drive DC-13 loads according to EN 60947-5-1
- Designed to meet IEC 61131-2, IEC 61000-4-2, IEC 61000-4-4, IEC 61000-4-5
- PowerSSO-24 package

### Applications

- Programmable logic control
- Industrial PC peripheral input/output
- Numerical control machines
- General high-side switch applications

### Description

The **IPS2100TH** is a monolithic device made using STMicroelectronics VIPower technology, intended for driving resistive, inductive or capacitive loads with one side connected to the ground. Active VCC pin voltage clamp protects the device against low energy spikes.

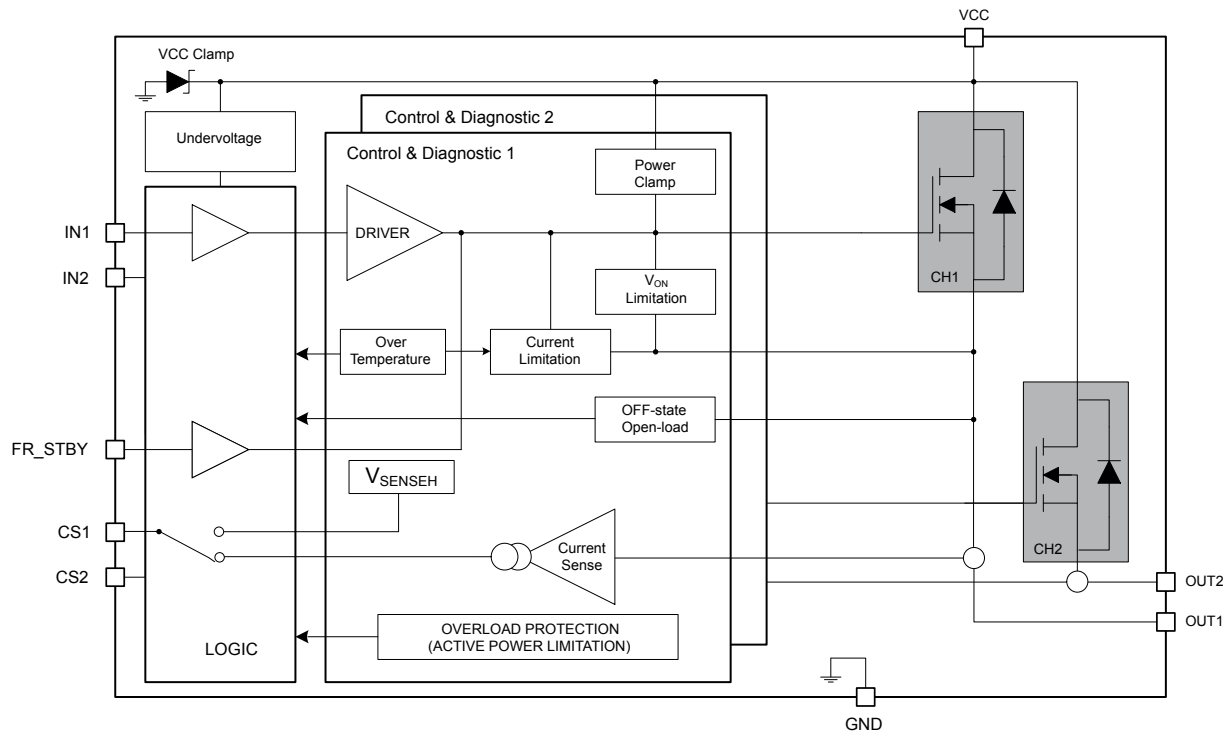
The device integrates an analog current sense, which delivers a current proportional to the load current. The sensed current of each output channel (1 and 2) is available on the correspondent current sense pin (CS1 and CS2).

Fault conditions such as overload, overtemperature, or short to VCC are reported via the current sense pins. Output current limitation protects the device in overload conditions. The device latches off in case of overload or thermal shutdown.

The FR\_STBY pin enables special thermal protection and power-saving management, allowing latch-off, auto-restart, and low-current standby operation.

## 1 Block diagram and pin description

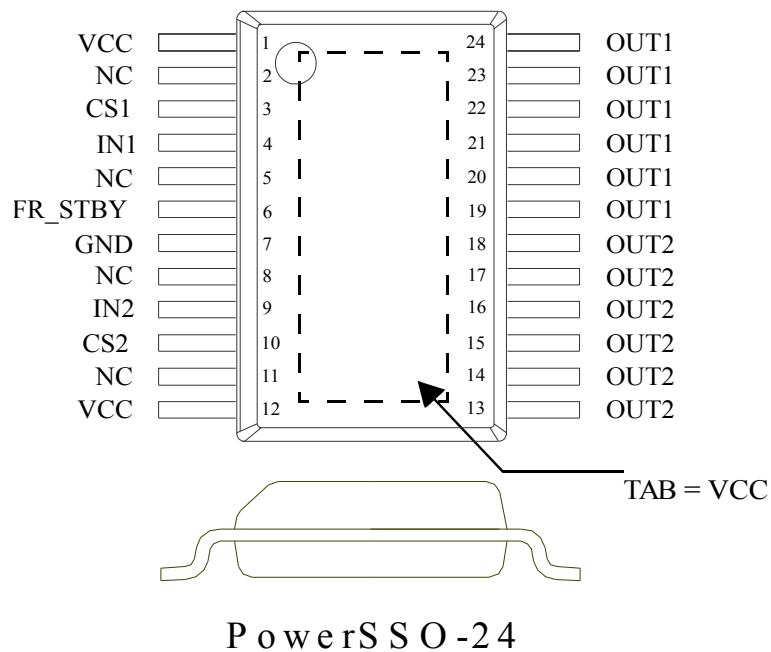
Figure 1. Block diagram



**Table 1. Pin function**

| Pin         | Name     | Type          | Function                                                                                                                                                                                                      |
|-------------|----------|---------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1, 12, TAB  | VCC      | Supply        | Power supply                                                                                                                                                                                                  |
| 3, 10       | CS1, CS2 | Analog output | Analog current sense pins, they deliver a current proportional to the load current                                                                                                                            |
| 4, 9        | IN1, IN2 | Logic input   | Voltage controlled input pins with hysteresis, CMOS compatible. They control output switch state                                                                                                              |
| 6           | FR_STBY  | Logic input   | In case of latch-off for overtemperature/overcurrent condition, a low pulse on the FR_STBY pin is needed to reset the channel.<br>The device enters in standby mode if all inputs and the FR_STBY pin are low |
| 7           | GND      | Supply        | Ground connection                                                                                                                                                                                             |
| 19 to 24    | OUT1     | Analog output | Power output channel 1                                                                                                                                                                                        |
| 13 to 18    | OUT2     | Analog output | Power output channel 2                                                                                                                                                                                        |
| 2, 5, 8, 11 | NC       | Not Connected |                                                                                                                                                                                                               |

**Figure 2. Configuration diagram PowerSSO-24 (top view)**



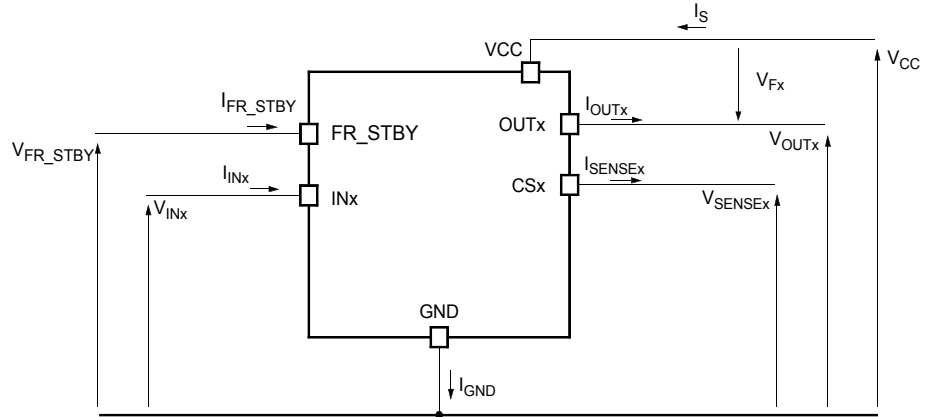
**Table 2. Suggested connections for unused and not connected pins**

| Connection/pin | Current Sense          | NC | Output          | Input                  | FR_STBY                |
|----------------|------------------------|----|-----------------|------------------------|------------------------|
| Floating       | Not Recommended        | X  | X               | X                      | X                      |
| To ground      | Through 10 kΩ resistor | X  | Not Recommended | Through 10 kΩ resistor | Through 10 kΩ resistor |

**Note:** X = don't care.

## 2 Electrical specification

**Figure 3. Current and voltage conventions**



Note:  $V_{Fx} = V_{OUTx} - V_{CC}$  during reverse polarity condition ( $x = 1, 2$ ).

### 2.1 Absolute maximum ratings

Stressing the device above the ratings listed in the [Table 3](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to the conditions reported in this section for extended periods may affect device reliability.

**Table 3. Absolute maximum ratings**

| Symbol               | Parameter                                                                                                                                                                         |                 | Value                                 | Unit |
|----------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------|---------------------------------------|------|
| V <sub>CC</sub>      | DC supply voltage                                                                                                                                                                 |                 | 56                                    | V    |
| -V <sub>CC</sub>     | Reverse DC supply voltage                                                                                                                                                         |                 | 0.3                                   | V    |
| -I <sub>GND</sub>    | DC reverse ground pin current                                                                                                                                                     |                 | 200                                   | mA   |
| I <sub>OUTx</sub>    | DC output current                                                                                                                                                                 |                 | Internally limited                    | A    |
| -I <sub>OUTx</sub>   | Reverse DC output current                                                                                                                                                         |                 | 30                                    | A    |
| I <sub>INx</sub>     | DC input current                                                                                                                                                                  |                 | -1 to 10                              | mA   |
| I <sub>FR_STBY</sub> | Fault reset standby DC input current                                                                                                                                              |                 | -1 to 1.5                             | mA   |
| -I <sub>SENSEx</sub> | DC reverse CS pin current                                                                                                                                                         |                 | 200                                   | mA   |
| V <sub>SENSEx</sub>  | Current sense maximum voltage                                                                                                                                                     |                 | V <sub>DEMAG</sub> to V <sub>CC</sub> | V    |
| E <sub>MAX</sub>     | Maximum switching energy<br>L = 50 mH; V <sub>CC</sub> = 32 V; T <sub>Jstart</sub> = 150 °C; I <sub>OUT</sub> = 2 A                                                               |                 | 210                                   | mJ   |
| L <sub>smax</sub>    | Maximum stray inductance in short circuit condition<br>R <sub>L</sub> = 300 mΩ, V <sub>CC</sub> = 32 V, T <sub>Jstart</sub> = 150 °C, I <sub>OUT</sub> = I <sub>limH</sub> (max.) |                 | 40                                    | μH   |
| V <sub>ESD</sub>     | Electrostatic discharge (human body model: R = 1.5 kΩ, C = 100 pF)                                                                                                                | IN1, 2          | 4000                                  | V    |
|                      |                                                                                                                                                                                   | CS1, 2          | 2000                                  |      |
|                      |                                                                                                                                                                                   | FR_STBY         | 4000                                  |      |
|                      |                                                                                                                                                                                   | OUT1, 2         | 5000                                  |      |
|                      |                                                                                                                                                                                   | V <sub>CC</sub> | 5000                                  |      |
| T <sub>J</sub>       | Junction operating temperature                                                                                                                                                    |                 | -40 to 150                            | °C   |
| T <sub>STG</sub>     | Storage temperature                                                                                                                                                               |                 | -55 to 150                            | °C   |

## 2.2 Thermal data

**Table 4. Thermal data**

| Symbol     | Parameter                                                  | Value                         | Unit |
|------------|------------------------------------------------------------|-------------------------------|------|
| $R_{thJC}$ | Thermal resistance, junction-to-case (with one channel ON) | 2.4                           | °C/W |
| $R_{thJA}$ | Thermal resistance, junction-to-ambient                    | See <a href="#">Figure 33</a> | °C/W |

## 2.3

### Electrical characteristics

8 V < V<sub>CC</sub> < 36 V, -40 °C < T<sub>J</sub> < 150 °C, unless otherwise specified.

**Table 5. Power section**

| Symbol               | Parameter                              | Test conditions                                                                                                                                            | Min. | Typ.             | Max.             | Unit |
|----------------------|----------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------------------|------------------|------|
| V <sub>CC</sub>      | Operating supply voltage               |                                                                                                                                                            | 8    |                  | 36               | V    |
| V <sub>USD</sub>     | Undervoltage shutdown                  |                                                                                                                                                            |      | 3.5              | 5                | V    |
| V <sub>USDhyst</sub> | Undervoltage shutdown hysteresis       |                                                                                                                                                            |      | 0.5              |                  | V    |
| R <sub>ON</sub>      | On-state resistance <sup>(1)</sup>     | I <sub>OUT</sub> = 2 A, T <sub>J</sub> = 25 °C                                                                                                             |      | 50               |                  | mΩ   |
|                      |                                        | I <sub>OUT</sub> = 2 A, T <sub>J</sub> = 150 °C                                                                                                            |      |                  | 100              |      |
| V <sub>clamp</sub>   | Clamp voltage                          | I <sub>S</sub> = 20 mA                                                                                                                                     | 58   | 64               | 70               | V    |
| I <sub>LGND</sub>    | Output current at GND disconnection    | V <sub>CC</sub> = V <sub>IN</sub> = V <sub>GND</sub> = 24 V; V <sub>OUT</sub> = 0 V                                                                        |      |                  | 0.5              | mA   |
| I <sub>S</sub>       | Supply current                         | Off-state, V <sub>CC</sub> = 24 V, T <sub>J</sub> = 25 °C,<br>V <sub>IN</sub> = V <sub>OUT</sub> = V <sub>SENSE</sub> = 0 V,<br>V <sub>FR_STBY</sub> = 0 V |      | 2 <sup>(2)</sup> | 5 <sup>(2)</sup> | μA   |
|                      |                                        | On-state, V <sub>CC</sub> = 24 V,<br>V <sub>IN</sub> = 5 V, I <sub>OUT</sub> = 0 A                                                                         |      | 4.2              | 6                | mA   |
| I <sub>L(off)</sub>  | Off-state output current               | V <sub>IN</sub> = V <sub>OUT</sub> = 0 V,<br>V <sub>CC</sub> = 24 V, T <sub>J</sub> = 25 °C                                                                | 0    | 0.01             | 3                | μA   |
|                      |                                        | V <sub>IN</sub> = V <sub>OUT</sub> = 0 V,<br>V <sub>CC</sub> = 24 V, T <sub>J</sub> = 125 °C                                                               | 0    |                  | 5                |      |
| V <sub>F</sub>       | Output - V <sub>CC</sub> diode voltage | -I <sub>OUT</sub> = 2 A, T <sub>J</sub> = 150 °C                                                                                                           |      |                  | 0.7              | V    |

1. For each channel.
2. Power MOSFET leakage included.

**Table 6. Switching (V<sub>CC</sub> = 24 V, T<sub>J</sub> = 25 °C)**

| Symbol                                   | Parameter                                        | Test conditions       | Min. | Typ. | Max. | Unit |
|------------------------------------------|--------------------------------------------------|-----------------------|------|------|------|------|
| t <sub>d(on)</sub>                       | Turn-on delay time                               | R <sub>L</sub> = 12 Ω |      | 30   |      | μs   |
| t <sub>d(off)</sub>                      | Turn-off delay time                              | R <sub>L</sub> = 12 Ω |      | 40   |      | μs   |
| (dV <sub>OUT</sub> /dt) <sub>(on)</sub>  | Turn-on voltage slope                            | R <sub>L</sub> = 12 Ω |      | 0.7  |      | V/μs |
| (dV <sub>OUT</sub> /dt) <sub>(off)</sub> | Turn-off voltage slope                           | R <sub>L</sub> = 12 Ω |      | 0.8  |      | V/μs |
| W <sub>ON</sub>                          | Switching energy losses during t <sub>won</sub>  | R <sub>L</sub> = 12 Ω |      | 0.5  |      | mJ   |
| W <sub>OFF</sub>                         | Switching energy losses during t <sub>woff</sub> | R <sub>L</sub> = 12 Ω |      | 0.3  |      | mJ   |

**Table 7. Logic inputs**

| Symbol          | Parameter                    | Test conditions         | Min. | Typ. | Max. | Unit |
|-----------------|------------------------------|-------------------------|------|------|------|------|
| V <sub>IL</sub> | INPUT pin low level voltage  |                         |      |      | 0.9  | V    |
| I <sub>IL</sub> | INPUT pin low level current  | V <sub>IN</sub> = 0.9 V | 1    |      |      | μA   |
| V <sub>IH</sub> | INPUT pin high level voltage |                         | 2.1  |      |      | V    |
| I <sub>IH</sub> | INPUT pin high level current | V <sub>IN</sub> = 2.1 V |      |      | 10   | μA   |

| Symbol               | Parameter                      | Test conditions                                      | Min. | Typ. | Max. | Unit          |
|----------------------|--------------------------------|------------------------------------------------------|------|------|------|---------------|
| $V_{I(hyst)}$        | INPUT pin hysteresis voltage   |                                                      | 0.25 |      |      | V             |
| $V_{ICL}$            | INPUT pin clamp voltage        | $I_{IN} = 1\text{ mA}$                               | 5.5  |      | 7    | V             |
|                      |                                | $I_{IN} = -1\text{ mA}$                              |      | -0.7 |      |               |
| $V_{FR\_STBY\_L}$    | FR_STBY pin low level voltage  |                                                      |      |      | 0.9  | V             |
| $I_{FR\_STBY\_L}$    | FR_STBY pin low level current  | $V_{FR\_STBY} = 0.9\text{ V}$                        | 1    |      |      | $\mu\text{A}$ |
| $V_{FR\_STBY\_H}$    | FR_STBY pin high level voltage |                                                      | 2.1  |      |      | V             |
| $I_{FR\_STBY\_H}$    | FR_STBY pin high level current | $V_{FR\_STBY} = 2.1\text{ V}$                        |      |      | 10   | $\mu\text{A}$ |
| $V_{FR\_STBY(hyst)}$ | FR_STBY pin hysteresis voltage |                                                      | 0.25 |      |      | V             |
| $V_{FR\_STBY\_CL}$   | FR_STBY pin clamp voltage      | $I_{FR\_STBY} = 15\text{ mA}$ ( $t < 10\text{ ms}$ ) | 11   |      | 15   | V             |
|                      |                                | $I_{FR\_STBY} = -1\text{ mA}$                        |      | -0.7 |      | V             |
| $t_{reset}$          | Overload latch-off reset time  | See <a href="#">Figure 23</a>                        | 2    |      | 24   | $\mu\text{s}$ |
| $t_{stby}$           | Standby delay                  | See <a href="#">Figure 24</a>                        | 120  |      | 1200 | $\mu\text{s}$ |

**Table 8. Protections and diagnostics**

| Symbol     | Parameter                                     | Test conditions                                                                                  | Min.          | Typ.          | Max.          | Unit               |
|------------|-----------------------------------------------|--------------------------------------------------------------------------------------------------|---------------|---------------|---------------|--------------------|
| $I_{limH}$ | DC short circuit current                      | $V_{CC} = 24\text{ V}$                                                                           | 24            | 34            | 46            | A                  |
|            |                                               | $5\text{ V} < V_{CC} < 36\text{ V}$                                                              |               |               | 46            |                    |
| $I_{limL}$ | Short circuit current during thermal cycling  | $V_{CC} = 24\text{ V}$ , $T_R < T_J < T_{TSD}$                                                   |               | 8.5           |               | A                  |
| $T_{TSD}$  | Shutdown temperature                          |                                                                                                  | 150           | 175           | 200           | $^{\circ}\text{C}$ |
| $T_R$      | Reset temperature                             |                                                                                                  | $T_{RS} + 1$  | $T_{RS} + 5$  |               | $^{\circ}\text{C}$ |
| $T_{RS}$   | Thermal reset status threshold <sup>(1)</sup> |                                                                                                  | 135           |               |               | $^{\circ}\text{C}$ |
| $T_{HYST}$ | Thermal hysteresis ( $T_{TSD} - T_R$ )        |                                                                                                  |               | 7             |               | $^{\circ}\text{C}$ |
| $V_{DEMG}$ | Turn-off output voltage clamp                 | $I_{OUT} = 2\text{ A}$ , $V_{IN} = 0\text{ V}$ , $L = 6\text{ mH}$                               | $V_{CC} - 58$ | $V_{CC} - 64$ | $V_{CC} - 70$ | V                  |
| $V_{ON}$   | Output voltage drop limitation                | $I_{OUT} = 100\text{ mA}$ , $T_J = -40\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$ |               | 25            |               | mV                 |

1. See [Section 3.1.3: Thermal shutdown](#) for details.

**Table 9. Current sense ( $8\text{ V} < V_{CC} < 36\text{ V}$ )**

| Symbol                              | Parameter                 | Test conditions                                                                                                             | Min. | Typ. | Max. | Unit |
|-------------------------------------|---------------------------|-----------------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| $K_{OL}$                            | $I_{OUT}/I_{SENSE}$       | $I_{OUT} = 10\text{ mA}$ , $V_{SENSE} = 0.5\text{ V}$ , $T_J = -40\text{ }^{\circ}\text{C}$                                 | 564  | 2800 | 5563 |      |
|                                     |                           | $I_{OUT} = 10\text{ mA}$ , $V_{SENSE} = 0.5\text{ V}$ , $T_J = 25\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$ | 972  |      | 4895 |      |
| $K_{LED}$                           | $I_{OUT}/I_{SENSE}$       | $I_{OUT} = 50\text{ mA}$ , $V_{SENSE} = 0.5\text{ V}$ , $T_J = -40\text{ }^{\circ}\text{C}$                                 | 1193 | 2650 | 4268 |      |
|                                     |                           | $I_{OUT} = 50\text{ mA}$ , $V_{SENSE} = 0.5\text{ V}$ , $T_J = 25\text{ }^{\circ}\text{C}$ to $150\text{ }^{\circ}\text{C}$ | 1416 |      | 3958 |      |
| $\frac{dK_{LED}}{K_{LEDTOT}}^{(1)}$ | Current sense ratio drift | $I_{OUT} = 12\text{ mA}$ to $60\text{ mA}$ , $I_{CAL} = 35\text{ mA}$ , $V_{SENSE} = 0.5\text{ V}$                          | -35  |      | 35   | %    |

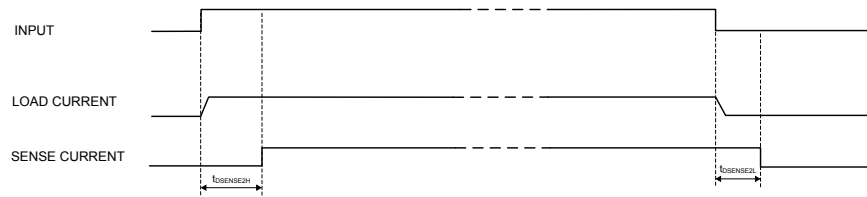
| Symbol                | Parameter                                                                                  | Test conditions                                                                                                                                                                        | Min. | Typ. | Max. | Unit          |
|-----------------------|--------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $K_0$                 | $I_{OUT}/I_{SENSE}$                                                                        | $I_{OUT} = 100 \text{ mA}$ , $V_{SENSE} = 0.5 \text{ V}$ , $T_J = -40^\circ\text{C}$ to $150^\circ\text{C}$                                                                            | 1409 | 2540 | 3726 |               |
| $dK_0/K_0^{(2)}$      | Current sense ratio drift                                                                  | $I_{OUT} = 100 \text{ mA}$ , $V_{SENSE} = 0.5 \text{ V}$ , $T_J = -40^\circ\text{C}$ to $150^\circ\text{C}$                                                                            | -20  |      | 20   | %             |
| $K_1$                 | $I_{OUT}/I_{SENSE}$                                                                        | $I_{OUT} = 0.7 \text{ A}$ , $V_{SENSE} = 2 \text{ V}$ , $T_J = -40^\circ\text{C}$ to $150^\circ\text{C}$                                                                               | 1597 | 2190 | 2764 |               |
| $dK_1/K_1^{(2)}$      | Current sense ratio drift                                                                  | $I_{OUT} = 0.7 \text{ A}$ , $V_{SENSE} = 2 \text{ V}$ , $T_J = -40^\circ\text{C}$ to $150^\circ\text{C}$                                                                               | -15  |      | 15   | %             |
| $K_2$                 | $I_{OUT}/I_{SENSE}$                                                                        | $I_{OUT} = 2 \text{ A}$ , $V_{SENSE} = 2 \text{ V}$ , $T_J = -40^\circ\text{C}$ to $150^\circ\text{C}$                                                                                 | 1850 | 2190 | 2550 |               |
| $dK_2/K_2^{(2)}$      | Current sense ratio drift                                                                  | $I_{OUT} = 2 \text{ A}$ , $V_{SENSE} = 2 \text{ V}$ , $T_J = -40^\circ\text{C}$ to $150^\circ\text{C}$                                                                                 | -10  |      | 10   | %             |
| $K_3$                 | $I_{OUT}/I_{SENSE}$                                                                        | $I_{OUT} = 8 \text{ A}$ , $V_{SENSE} = 4 \text{ V}$ , $T_J = -40^\circ\text{C}$ to $150^\circ\text{C}$                                                                                 | 2050 | 2190 | 2280 |               |
| $dK_3/K_3^{(2)}$      | Current sense ratio drift                                                                  | $I_{OUT} = 8 \text{ A}$ , $V_{SENSE} = 4 \text{ V}$ , $T_J = -40^\circ\text{C}$ to $150^\circ\text{C}$                                                                                 | -3   |      | 3    | %             |
| $I_{SENSE0}$          | Analog sense leakage current                                                               | $I_{OUT} = 0 \text{ A}$ , $V_{SENSE} = 0 \text{ V}$ , $V_{IN} = 0 \text{ V}$ , $T_J = -40^\circ\text{C}$ to $150^\circ\text{C}$                                                        | 0    |      | 1    | $\mu\text{A}$ |
|                       |                                                                                            | $I_{OUT} = 0 \text{ A}$ , $V_{SENSE} = 0 \text{ V}$ , $V_{IN} = 5 \text{ V}$ , $T_J = -40^\circ\text{C}$ to $150^\circ\text{C}$                                                        | 0    |      | 2    |               |
| $V_{SENSE}$           | Max. analog sense output voltage                                                           | $I_{OUT} = 8 \text{ A}$ , $R_{SENSE} = 3.9 \text{ k}\Omega$                                                                                                                            | 5    |      |      | V             |
| $V_{SENSEH}$          | Analog sense output voltage in fault condition <sup>(3)</sup>                              | $V_{CC} = 24 \text{ V}$ , $R_{SENSE} = 3.9 \text{ k}\Omega$                                                                                                                            | 7.5  | 8.5  | 9.5  | V             |
| $I_{SENSEH}$          | Analog sense output current in fault condition <sup>(3)</sup>                              | $V_{CC} = 24 \text{ V}$ , $V_{SENSE} = 5 \text{ V}$                                                                                                                                    | 4.9  | 7    | 12   | mA            |
| $t_{DSENSE2H}$        | Delay response time from rising edge of INPUT pins                                         | $V_{SENSE} < 4 \text{ V}$ , $0.15 \text{ A} < I_{OUT} < 8 \text{ A}$ ,<br>$I_{SENSE} = 90\%$ of $I_{SENSE} \text{ max}$ ,<br>(see Figure 4)                                            |      | 150  | 300  | $\mu\text{s}$ |
| $\Delta t_{DSENSE2H}$ | Delay response time between rising edge of output current and rising edge of current sense | $V_{SENSE} < 4 \text{ V}$ ,<br>$I_{SENSE} = 90\%$ of $I_{SENSE} \text{ max}$ ,<br>$I_{OUT} = 90\%$ of $I_{OUT} \text{ max}$ ,<br>$I_{OUT} \text{ max} = 2 \text{ A}$<br>(see Figure 7) |      |      | 250  | $\mu\text{s}$ |
| $t_{DSENSE2L}$        | Delay response time from falling edge of INPUT pins                                        | $V_{SENSE} < 4 \text{ V}$ ,<br>$0.15 \text{ A} < I_{OUT} < 8 \text{ A}$ ,<br>$I_{SENSE} = 10\%$ of $I_{SENSE} \text{ max}$<br>(see Figure 4)                                           |      | 5    | 20   | $\mu\text{s}$ |

1. Specified by design, not tested in production.
2. Specified by design, not tested in production.
3. Fault condition includes: power limitation, overtemperature and open-load in off-state condition.

**Table 10. Open-load detection ( $V_{FR\_STBY} = 5\text{ V}$ )**

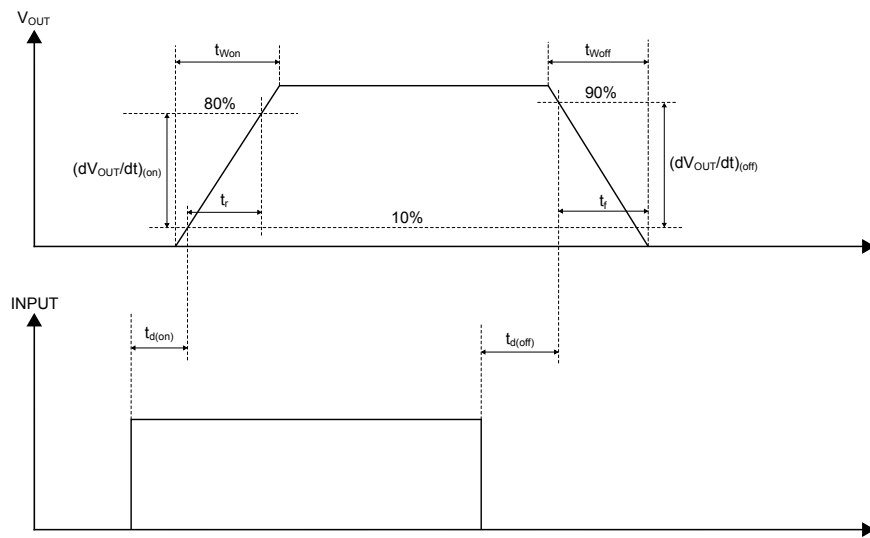
| Symbol           | Parameter                                                                      | Test conditions                                                                                                              | Min. | Typ. | Max. | Unit          |
|------------------|--------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $V_{OL}$         | Open-load off-state voltage detection threshold                                | $V_{IN} = 0\text{ V}$ , $8\text{ V} < V_{CC} < 36\text{ V}$<br>$V_{FR\_STBY} = 5\text{ V}$                                   | 2    |      | 4    | V             |
| $t_{DSTKON}$     | Output short circuit to $V_{CC}$ detection delay at turn off                   | See Figure 31                                                                                                                | 180  |      | 1800 | $\mu\text{s}$ |
| $I_{L(off2)}$    | Off-state output current at $V_{OUT} = 4\text{ V}$                             | $V_{IN} = 0\text{ V}$ , $V_{SENSE} = 0\text{ V}$ ,<br>$V_{OUT}$ rising from $0\text{ V}$ to $4\text{ V}$ ,                   | -120 |      | 0    | $\mu\text{A}$ |
| $t_{d\_vol}$     | Delay response from output rising edge to $V_{SENSE}$ rising edge in open-load | $V_{OUT} = 4\text{ V}$ , $V_{IN} = 0\text{ V}$ ,<br>$V_{SENSE} = 90\%$ of $V_{SENSEH}$ ,<br>$R_{SENSE} = 3.9\text{ k}\Omega$ |      |      | 20   | $\mu\text{s}$ |
| $t_{DFRSTK\_ON}$ | Output short circuit to $V_{CC}$ detection delay at $FR\_STBY$ activation      | Input1,2 = low<br>(see Figure 6)                                                                                             |      |      | 50   | $\mu\text{s}$ |

**Figure 4. Current sense delay characteristics**



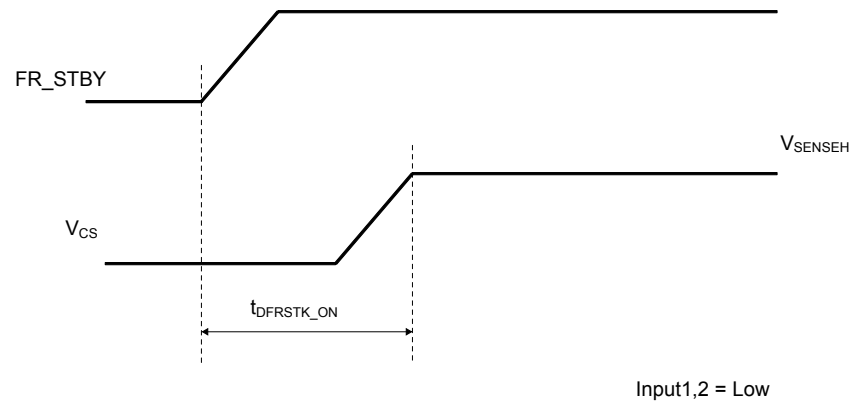
GAPGCFT000117

**Figure 5. Switching characteristics**

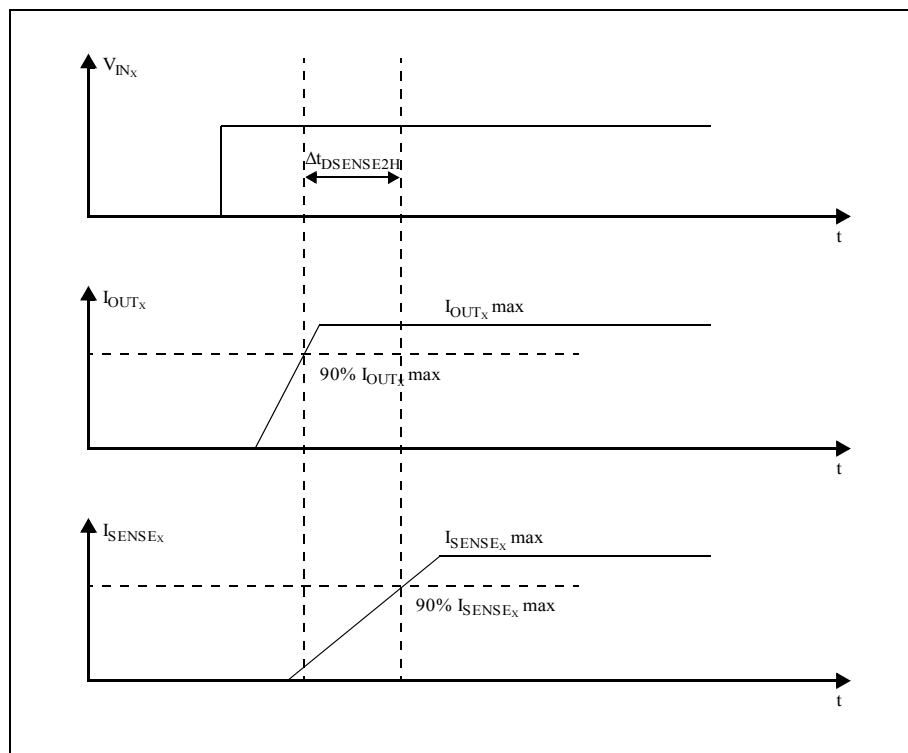


GAPGCFT000114

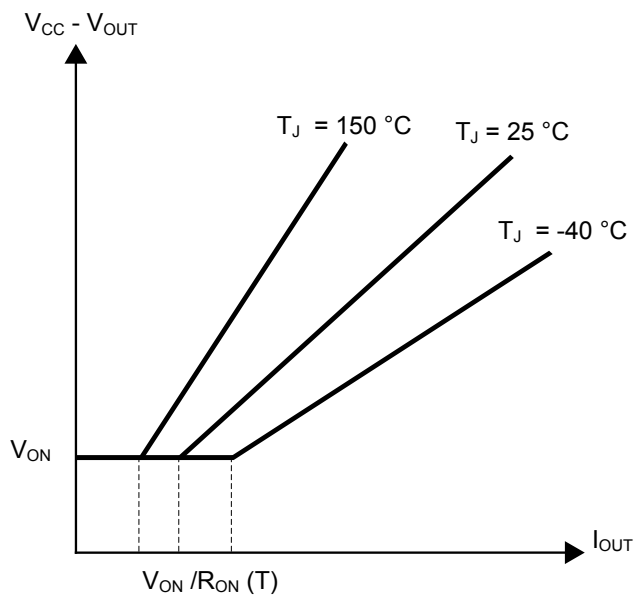
**Figure 6. Output stuck to  $V_{CC}$  detection delay time at FR\_STBY activation**



**Figure 7. Delay response time between rising edge of output current and rising edge of current sense for each channel (CSx enabled)**



**Figure 8. Output voltage drop limitation**



AG00074V1

## 2.4 Electrical characteristics (curves)

Figure 9. Off-state output current

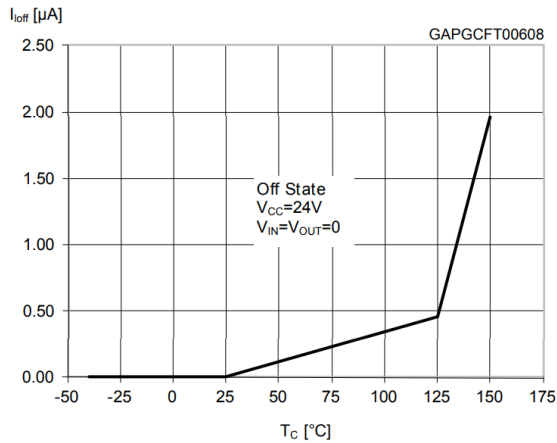


Figure 10. High level input current

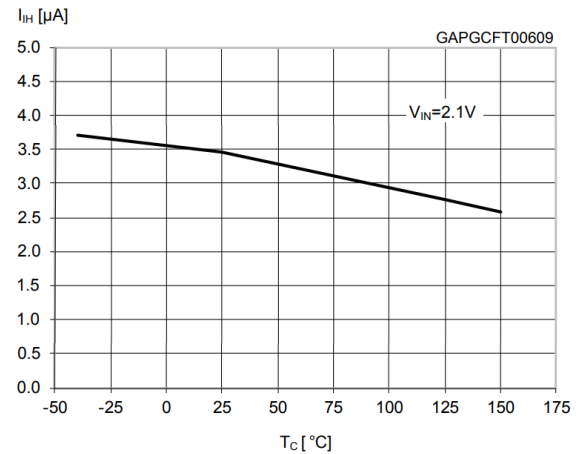


Figure 11. Input clamp voltage

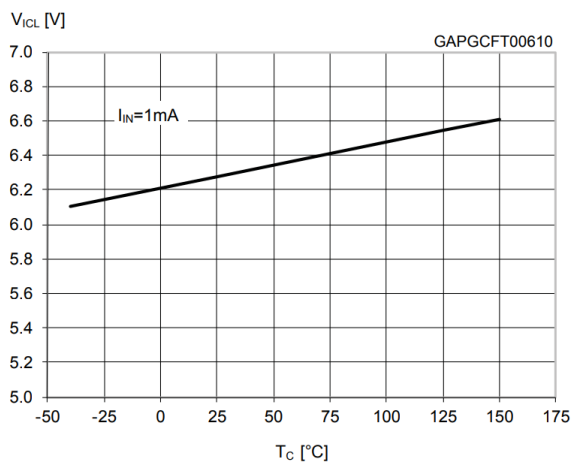


Figure 12. Low level input voltage

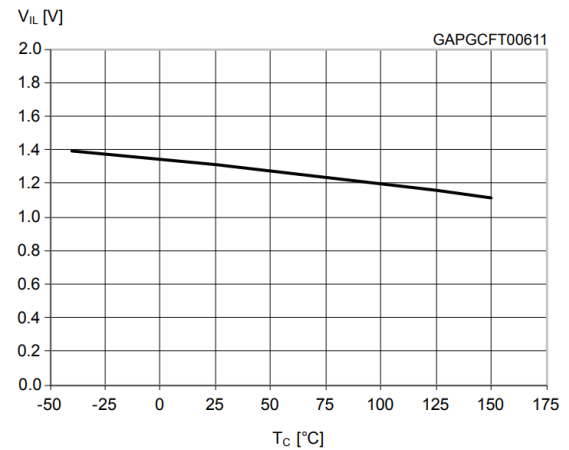


Figure 13. High level input voltage

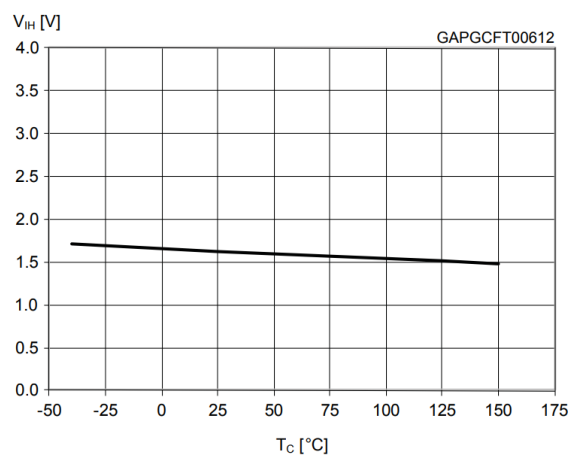
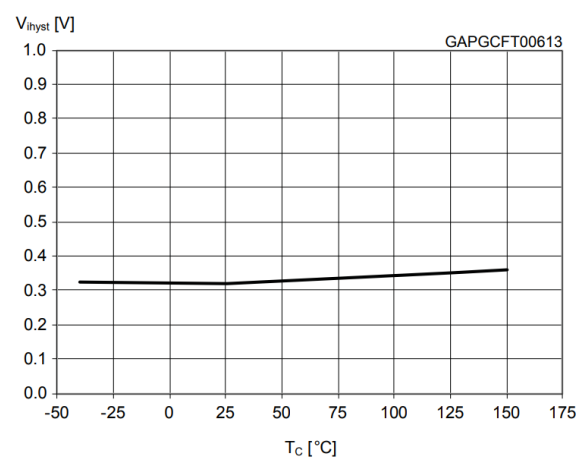
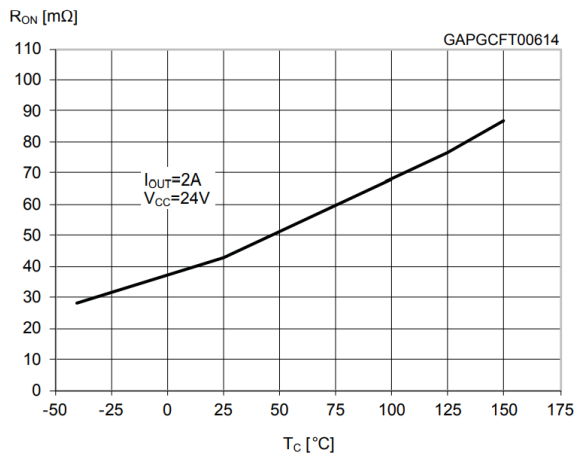


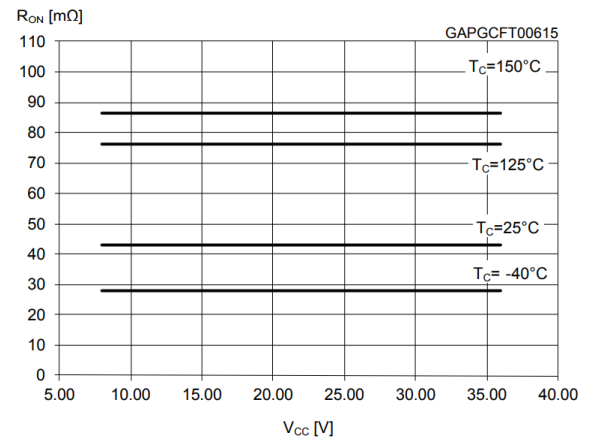
Figure 14. Input hysteresis voltage



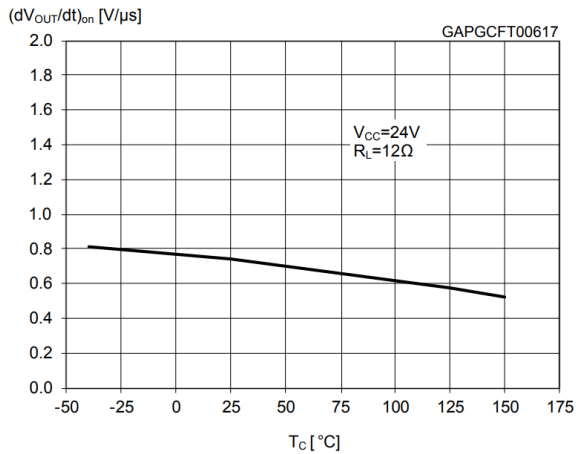
**Figure 15. On-state resistance vs  $T_C$**



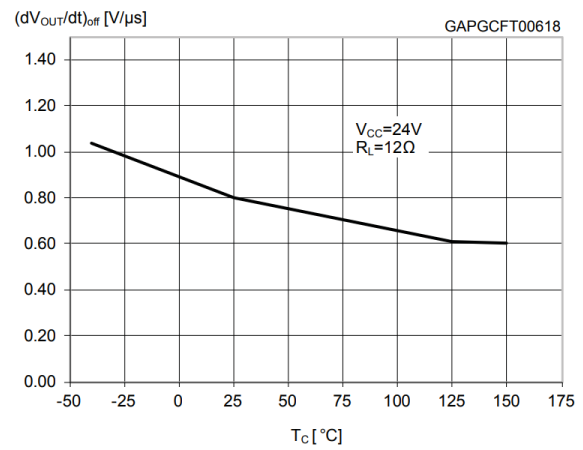
**Figure 16. On-state resistance vs  $V_{CC}$**



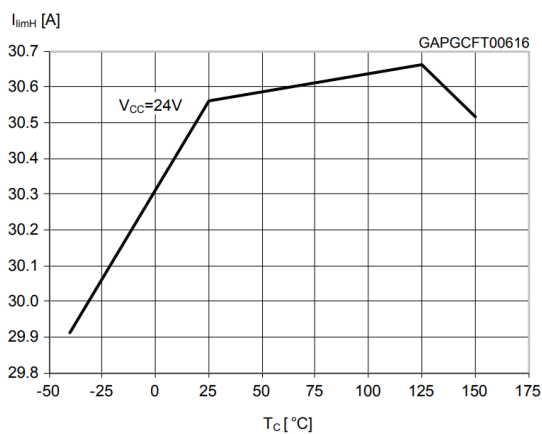
**Figure 17. Turn-on voltage slope**



**Figure 18. Turn-off voltage slope**



**Figure 19.  $I_{limH}$  vs  $T_C$**



## 3 Protections

### 3.1 Thermal protections

To reduce the effects of excessive power dissipation and consequent thermal stress, the device implements a sophisticated overload/short circuit management.

#### 3.1.1 Current limitation

The device is equipped with an output current limiter in order to protect the silicon from excessive current flow. Consequently, in case of short-circuit or overload, the output current is clamped to a safety level,  $I_{limH}$ ; in case the device enters thermal cycling a lower current limitation level,  $I_{limL}$ , is triggered.

#### 3.1.2 Power limitation

The basic working principle of this protection consists of an indirect measurement of the junction temperature swing through the direct measurement of the spatial temperature gradient on the device surface.

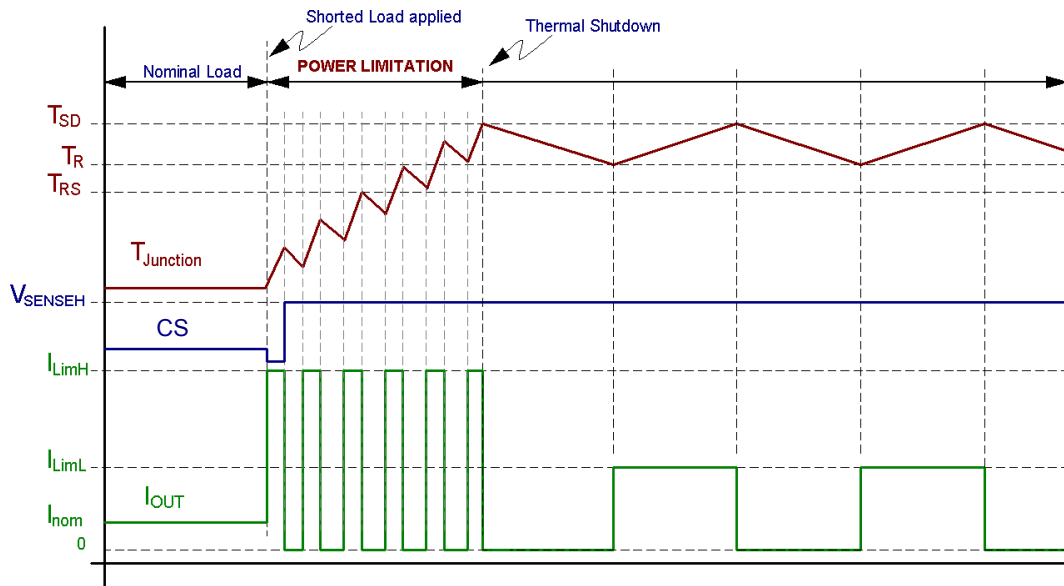
When the gradient temperature exceeds a safety threshold, output MOSFET is automatically turned off and the CS pin indicates a thermal intervention bringing the voltage on the CSx pin to the  $V_{SENSEH}$  value.

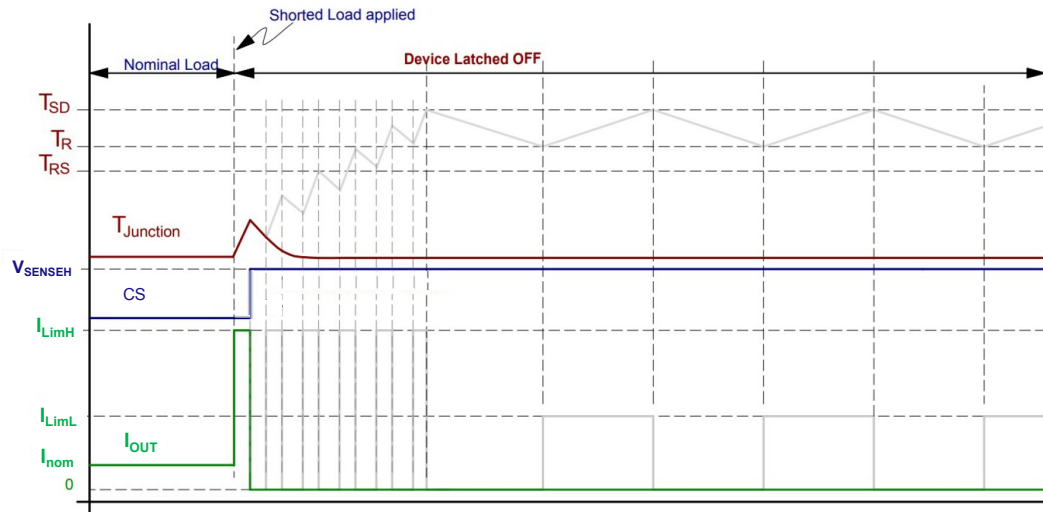
The device starts cool down and, based on the FR\_STBY pin status, the output MOSFET switches on and cycles with a thermal hysteresis, limiting at  $I_{limH}$ , according to the maximum instantaneous power which can be handled (FR\_STBY = Low) or remain off (FR\_STBY = High); (see also Reset and standby mechanism description.).

The protection prevents fast thermal transient effects.

Following figures show the mechanism previously described.

**Figure 20. Power limitation on a shorted load (FR\_STBY = Low)**



**Figure 21. Power limitation with latch (FR\_STBY = High)**


### 3.1.3 Thermal shutdown

If the device junction temperature exceeds the  $T_{SD}$  threshold, the affected output is turned off.

Based on the FR\_STBY pin status, the device enters thermal cycling operation (FR\_STBY = Low) or remains off (FR\_STBY = High) (see also [Section 4](#)).

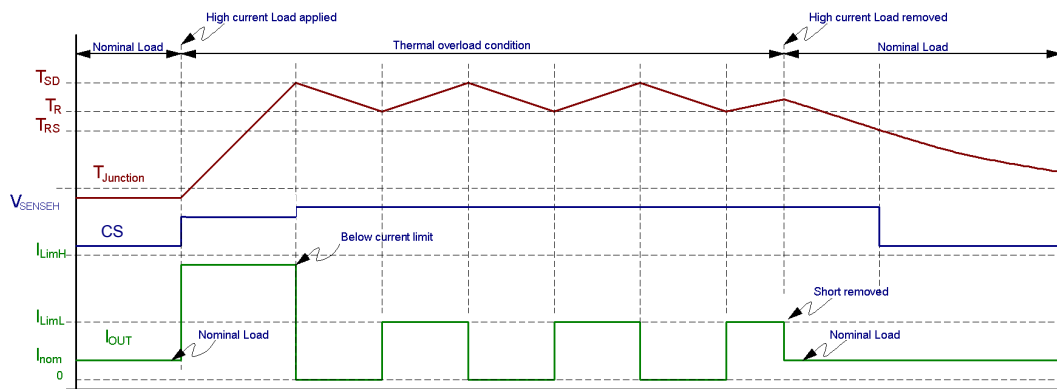
In the first case, the current is limited to  $I_{limL}$  and a fault condition is indicated on CSx, unless already asserted due to power limitation.

The output remains off until the junction temperature falls below the thermal reset temperature,  $T_R$ . The driver then automatically restarts and continues to limit the current at  $I_{limL}$  until the thermal shutdown condition is reached again. The thermal cycling process repeats until the overload condition is removed.

When the temperature decreases under  $T_{RS}$ , the fault condition is removed.

$T_{RS}$  is lower than  $T_R$  to ensure a stable fault indication during a faulty load condition.

The following figure shows the thermal shutdown response.

**Figure 22. Thermal shutdown response (no power limitation) (FR\_STBY = Low)**


## 3.2 Negative voltage clamp

In case the device drives inductive load, the output voltage reaches a negative value during turn off. A negative voltage clamp structure limits the maximum negative voltage to a certain value,  $V_{DEMG}$ , allowing the inductor energy to be dissipated without damaging the device (see also [Section 5](#)).

## 4 Reset and standby mechanism description

The **IPS2100TH** features a special thermal protection and power saving mechanism controlled by the **FR\_STBY** pin. In the event of an overload, when the **FR\_STBY** pin is high (default state), the device turns off the affected channel and does not attempt to turn it back on, even if the temperature drops or the load returns to normal; the device enters **latch-off mode**.

At the same time, the voltage on the **CS<sub>x</sub>** pin rises to the **V<sub>SENSEH</sub>** value.

Recovery from an overload and reactivation of the outputs are managed through the **FR\_STBY** pin: applying a low pulse for a minimum specified time (**t<sub>reset</sub>**) resets the latch-off condition (fault reset) and triggers a new attempt to activate the channel, as shown in [Figure 23](#).

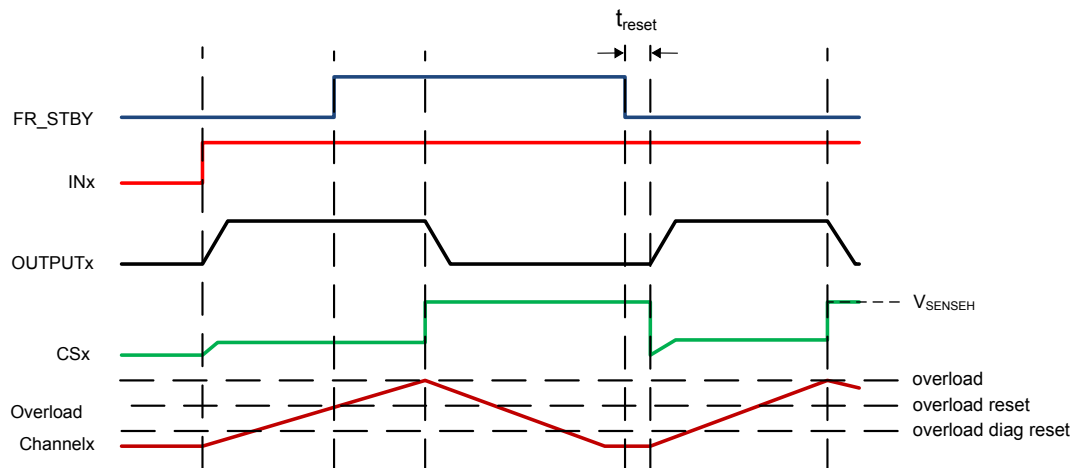
If the **FR\_STBY** pin remains low after the reset pulse, the device enters **auto-restart mode**. On the contrary, if **FR\_STBY** is set high, the device remains inactive (see [Figure 25](#)).

When **FR\_STBY** is kept low together with **IN1** and **IN2**, the device enters **standby mode**, allowing minimum current consumption, **I<sub>S(off-state)</sub>** (see [Figure 24](#)).

Figure 3 shows the device's behavior under overload conditions as a function of the possible combinations of the **FR\_STBY** and **IN<sub>x</sub>** signals.

The possible device mode and related pins status/values are summarized in [Table 11](#).

**Figure 23. t<sub>reset</sub> definition**



**Figure 24. t<sub>stby</sub> definition**

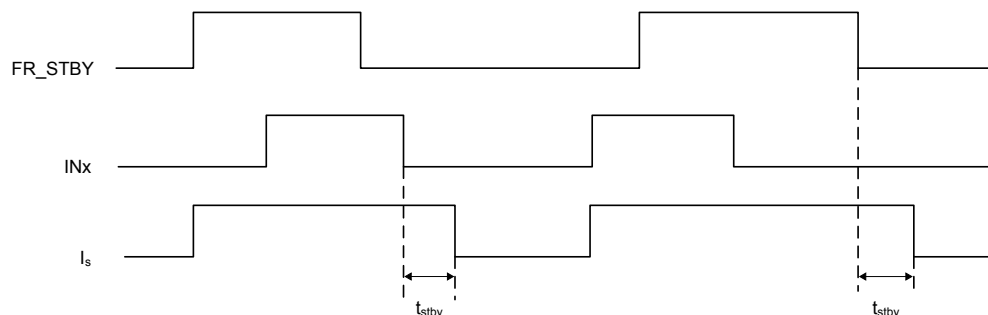
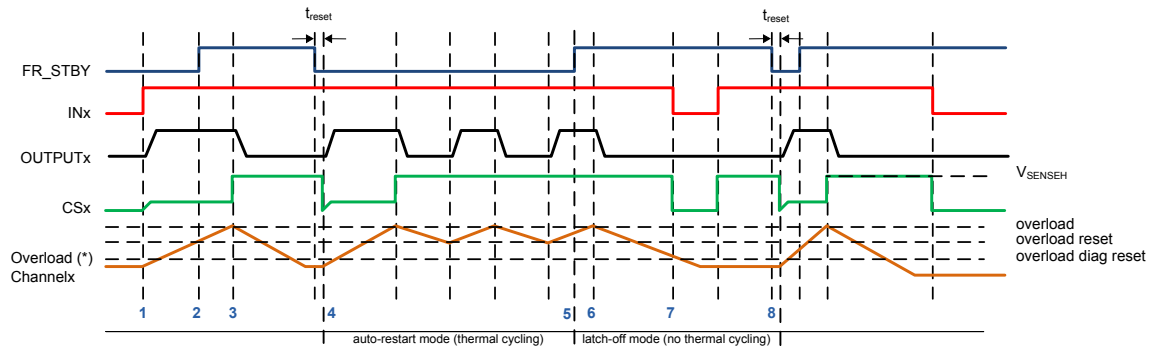


Figure 25. Device behavior in overload condition



- 1: OUTPUTx and CSx controlled by INx
- 2: FR\_STBY from '0' to '1' → no action on CSx pin
- 3: Overload latch-off. INn high → CSx high
- 4: FR\_STBY low AND Temp channel x < overload\_reset → overload latch reset after t\_reset
- 4 to 5: FR\_STBY low AND INx high → thermal cycling, CSx high
- 5: FR\_STBY high → latch-off reset disabled
- 6 to 7: Overload event and FR\_STBY high → latch-off, no thermal cycling
- 7 to 8: Overload diagnostic disabled/enabled by the input
- 8: Overload latch-off reset by FR\_STBY

(\*) Overload = thermal shutdown or power limitation

Table 11. Functional table

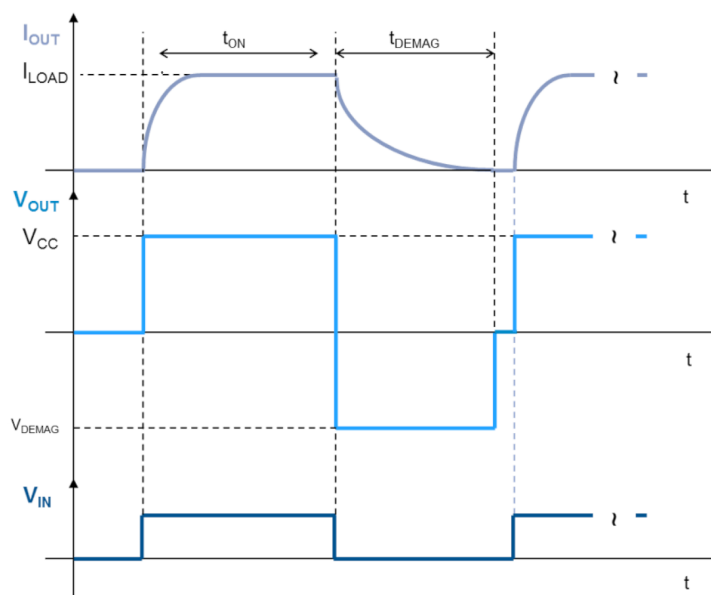
| Device status                      | FR_STBY | IN <sub>x</sub> | OUT <sub>x</sub> | CS <sub>x</sub>     |
|------------------------------------|---------|-----------------|------------------|---------------------|
| Standby                            | L       | L               | L                | 0                   |
| Normal operation                   | X       | L               | L                | 0                   |
|                                    | X       | H               | H                | Nominal             |
| Overload                           | X       | L               | L                | 0                   |
|                                    | X       | H               | H                | > Nominal           |
| Overtemperature/short to ground    | X       | L               | L                | 0                   |
|                                    | L       | H               | Cycling          | V <sub>SENSEH</sub> |
|                                    | H       | H               | Latched          | V <sub>SENSEH</sub> |
| Undervoltage                       | X       | X               | L                | 0                   |
| Short to V <sub>CC</sub>           | L       | L               | H                | 0                   |
|                                    | H       | L               | H                | V <sub>SENSEH</sub> |
|                                    | X       | H               | H                | < Nominal           |
| Open-load off-state (with pull-up) | L       | L               | H                | 0                   |
|                                    | H       | L               | H                | V <sub>SENSEH</sub> |
|                                    | X       | H               | H                | 0                   |
| Negative output voltage clamp      | X       | L               | Negative         | 0                   |

## 5 Active clamp

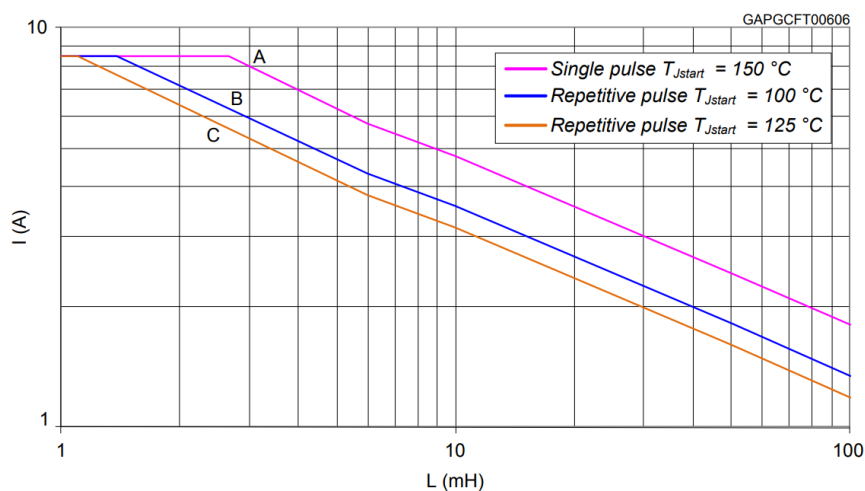
Active clamp is also known as **Fast Demagnetization of inductive loads** or **Fast Current Decay**. When a high-side driver turns off an inductance, an undervoltage on the output is detected (see Figure 26).

The OUT pin is pulled down to  $V_{\text{DEMAG}}$ . The conduction state is modulated by an internal circuitry in order to keep the OUT pin voltage at  $\sim V_{\text{DEMAG}}$  until the load energy has been dissipated. The energy is dissipated in both IC internal switch and load resistance.

**Figure 26. Active clamp typical waveforms**



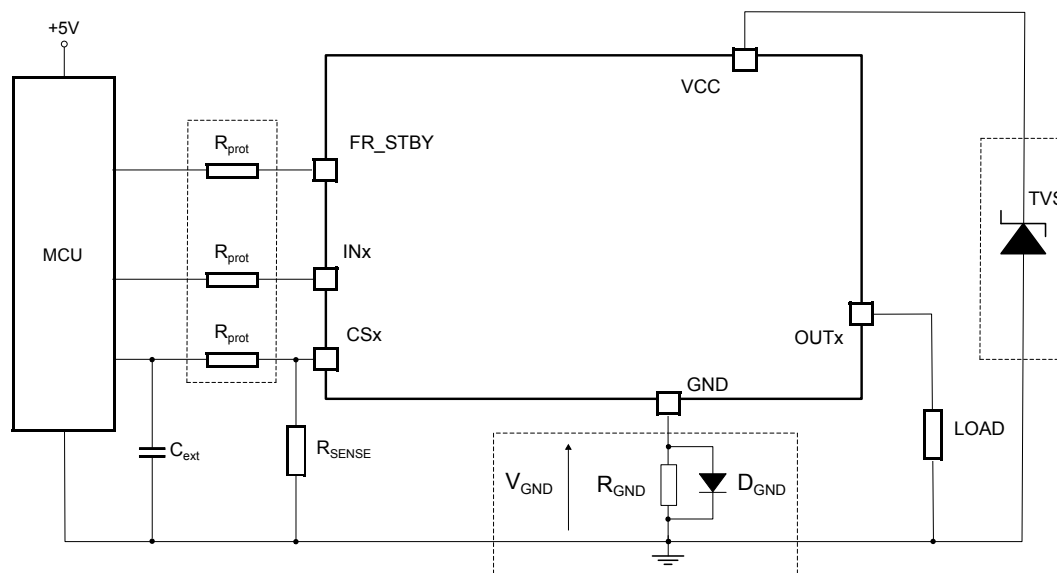
**Figure 27. Maximum turn off current versus inductance**



**Note:** Values are generated with  $R_L = 0 \Omega$ . In case of repetitive pulses,  $T_{Jstart}$  (at the beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves A and B.

## 6 Application information

Figure 28. Application schematic



### 6.1 GND protection network against reverse polarity

#### 6.1.1 Solution 1: resistor in the ground line (R<sub>GND</sub> only)

This solution can be used with any load type.

The following is an indication on how to dimension the R<sub>GND</sub> resistor.

1.  $R_{GND} \leq 600 \text{ mV} / (I_{S(on)max.})$
2.  $R_{GND} \geq (-V_{CC}) / (-I_{GND})$

Where  $-I_{GND}$  is the DC reverse ground pin current and can be found in the absolute maximum rating section of the device datasheet.

Power dissipation in R<sub>GND</sub> (when  $V_{CC} < 0 \text{ V}$ : during reverse polarity) is:

$$P_D = (-V_{CC})^2 / R_{GND}$$

This resistor can be shared among several different HSDs. Please note that the value of this resistor should be calculated with formula (1) where  $I_{S(on)max.}$  becomes the sum of the maximum on-state currents of the different devices.

Please note that if the microprocessor ground is not shared by the device ground then the R<sub>GND</sub> produces a shift ( $I_{S(on)max.} \cdot R_{GND}$ ) in the input thresholds and the status output values. This shift varies depending on how many devices are ON in the case of several high side drivers sharing the same R<sub>GND</sub>.

If the calculated power dissipation results in a large resistor value or requires several devices to share the same resistor, ST recommends implementing solution 2 (see below).

#### 6.1.2 Solution 2: diode (D<sub>GND</sub>) in the ground line

A resistor (R<sub>GND</sub> = 4.7 kΩ) should be inserted in parallel with D<sub>GND</sub> if the device drives an inductive load.

This small signal diode can be safely shared among several different HSDs. Also in this case, the presence of the ground network produces a shift ( $\approx 600 \text{ mV}$ ) in the input threshold and in the status output values, if the microprocessor ground is not common to the device ground. This shift does not vary if more than one HSD shares the same diode/resistor network.

### 6.2 Vcc overshoot protection

To protect the device from supply rail overshoot, a TVS is inserted between VCC and GND.

It will be chosen to protect the circuit but not interferes with its normal operations.

For this reason, the TVS must be selected with appropriate  $V_{BR}$  and  $V_{CL}$  values for the maximum operating voltage of the application.

### 6.3 MCU I/Os protection

If a ground protection network is used and a negative transient is present on the VCC line, the control pins are pulled negative. ST recommends placing a resistor ( $R_{prot}$ ) in series to protect the microcontroller I/O pins from latch-up.

The value of these resistors is a compromise between the leakage current of the microcontroller and the current required by the HSD I/Os (Input levels compatibility) with the latch-up limit of microcontroller I/Os.

#### Equation: $R_{prot}$ range calculation

$$-V_{CCpeak} / I_{latchup} \leq R_{prot} \leq (V_{OH\mu C} - V_{IH} - V_{GND}) / I_{IHmax}$$

#### Calculation example:

For  $V_{CCpeak} = -600$  V and  $I_{latchup} \geq 20$  mA;  $V_{OH\mu C} \geq 4.5$  V

$$30 \text{ k}\Omega \leq R_{prot} \leq 180 \text{ k}\Omega.$$

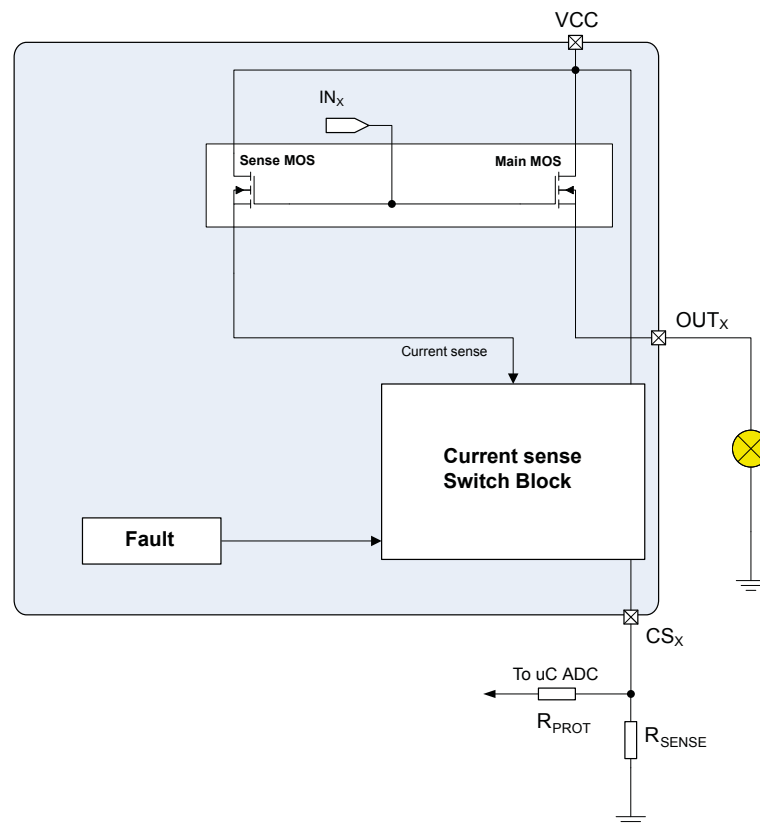
Recommended value:  $R_{prot} = 60 \text{ k}\Omega$ .

### 6.4 Analog current sense

Diagnostic information on device and load status are provided by the analog output pins (CS1, CS2).

#### 6.4.1 Principle of current sense signal generation

Figure 29. Current sense block diagram



### Current sense

The output is capable of providing:

- Current mirror proportional to the load current in normal operation, delivering current proportional to the load according to a known ratio named K
- Diagnostics flag in fault conditions delivering fixed voltage  $V_{SENSEH}$

The current delivered by the current sense circuit,  $I_{SENSE}$ , can be easily converted into a voltage  $V_{SENSE}$  by using an external sense resistor,  $R_{SENSE}$ , allowing continuous load monitoring and abnormal condition detection.

### Normal operation (channel ON, no fault)

While the device is operating in normal conditions (no fault intervention),  $V_{SENSE}$  calculation can be done using simple equations.

Current provided by  $CS_X$ :  $I_{SENSE} = I_{OUT} / K$

Voltage on  $R_{SENSE}$ :  $V_{SENSE} = R_{SENSE} \cdot I_{SENSE} = R_{SENSE} \cdot I_{OUT} / K$

Where:

- $V_{SENSE}$  is the voltage measurable on the  $R_{SENSE}$  resistor
- $I_{SENSE}$  is the current provided from  $CS_X$  pin in current output mode
- $I_{OUT}$  is the current flowing through output
- K factor represents the ratio between PowerMOS cells and SenseMOS cells; its spread includes geometric factor spread, current sense amplifier offset and process parameters spread of overall circuitry specifying the ratio between  $I_{OUT}$  and  $I_{SENSE}$ .

### Failure flag indication

In case of power limitation/over-temperature, the fault is indicated by the CS pin, which is switched to a "current limited" voltage source,  $V_{SENSEH}$ .

In any case, the current sourced by the  $CS_X$  pin in this condition is limited to  $I_{SENSEH}$ .

## 6.4.2 Short to VCC and OFF-state open-load detection

### Short to VCC

A short circuit between VCC and output is indicated by the relevant current sense pin set to  $V_{SENSEH}$  during the device off-state. Small or no current is delivered by the current sense during the on-state depending on the nature of the short-circuit.

### OFF-state open-load with external circuitry

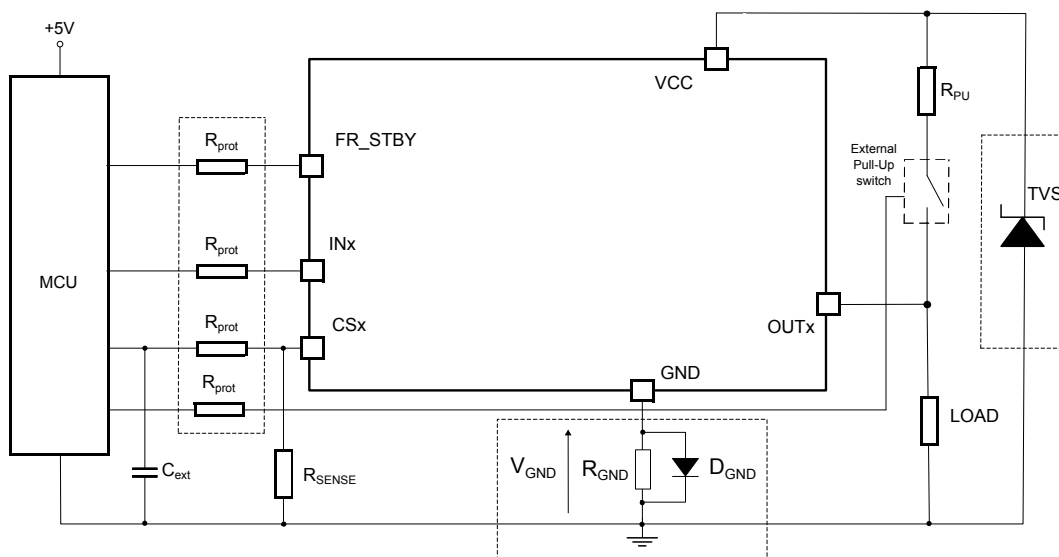
Detection of an open-load in off-state mode requires an external pull-up resistor  $R_{PU}$  connecting the output to a positive supply voltage  $V_{PU}$  (see [Figure 30](#)).

It is preferable that  $V_{PU}$  is switched off during the module standby mode in order to avoid the overall standby current consumption to increase in normal conditions, i.e. when load is connected.

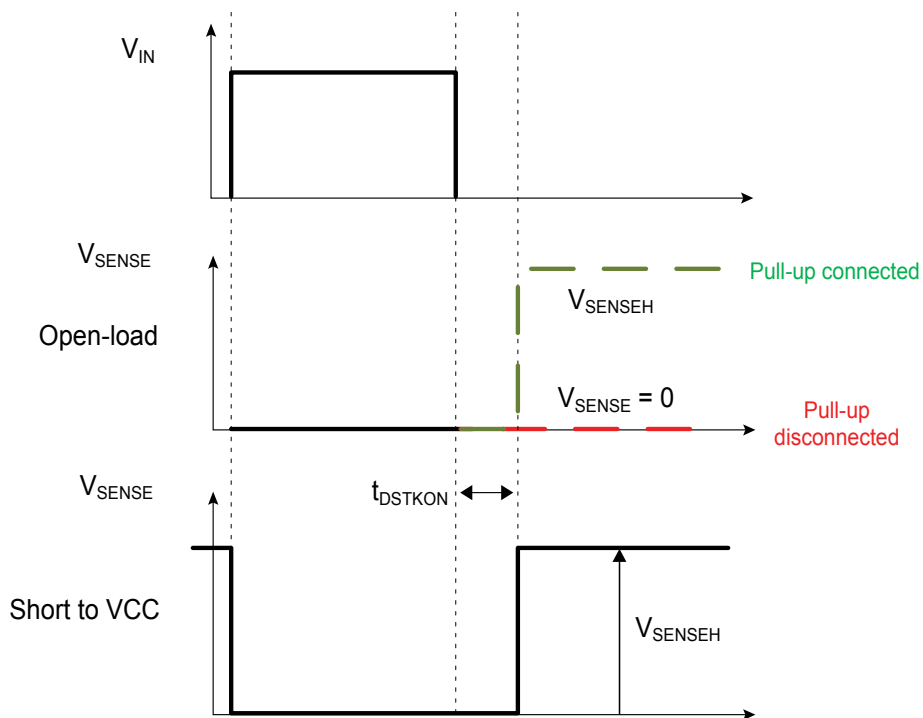
$R_{PU}$  must be selected in order to ensure  $V_{OUT} > V_{OLmax}$  in accordance with the following equation:

$$R_{PU} < (V_{PU} - 4) / I_{L(off2)min}$$

**Figure 30. Application schematic for open-load detection in off-state**



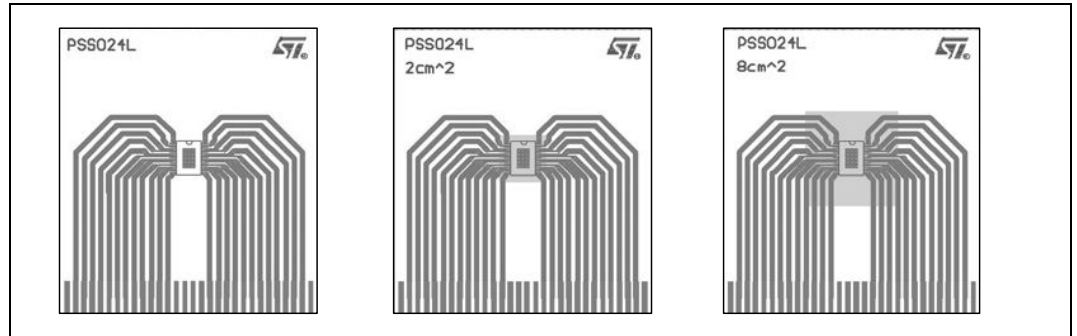
**Figure 31. Open-load / short to  $V_{CC}$  condition**



## 7 Package and PCB thermal data

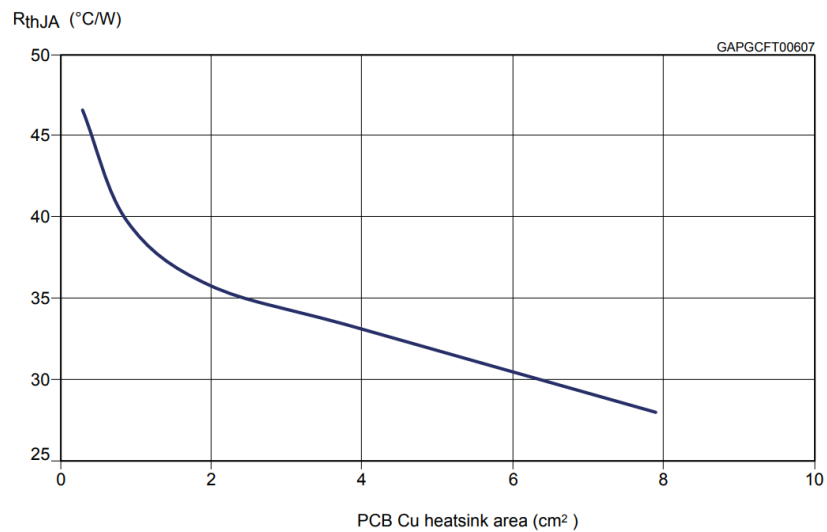
### 7.1 PowerSSO-24 thermal data

Figure 32. PowerSSO-24 PCB

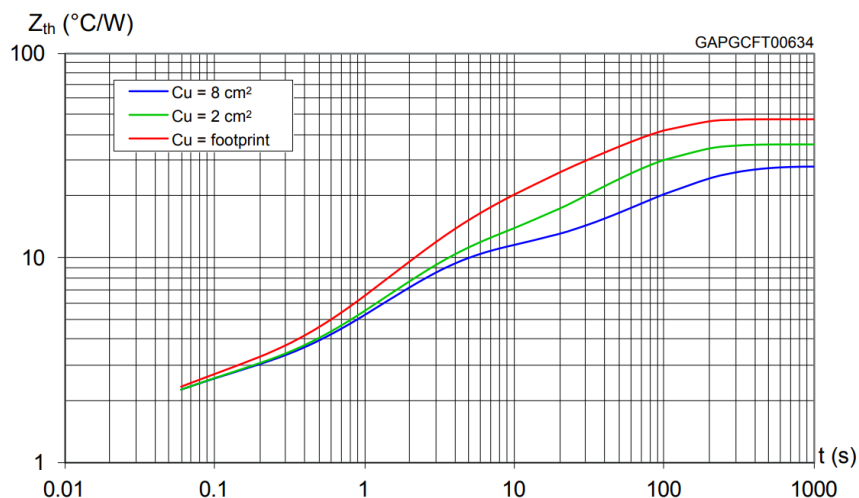


Note: Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (PCB: Double layer; Thermal Vias, FR4 area= 77 mm x 86 mm, PCB thickness=1.6mm, Cu thickness=70  $\mu$ m (front and back side), Copper areas: from minimum pad lay-out to 8 cm<sup>2</sup>).

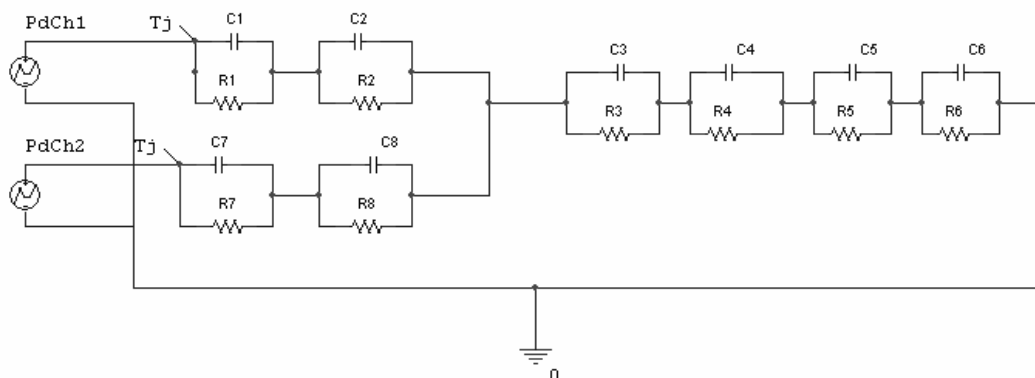
Figure 33.  $R_{thJA}$  vs PCB copper area in open box free air condition (one channel ON)



**Figure 34. PowerSSO-24 thermal impedance junction ambient single pulse (one channel ON)**



**Figure 35. Thermal fitting model of a quad channel HSD in PowerSSO-24**



The fitting model is a simplified thermal tool and is valid for transient evolutions where the embedded protections (power limitation or thermal cycling during thermal shutdown) are not triggered.

**Equation: pulse calculation formula**

$$Z_{th\delta} = R_{th} \cdot \delta + Z_{THtp} (1 - \delta)$$

where  $\delta = t_p / T$

**Table 12. Thermal parameters**

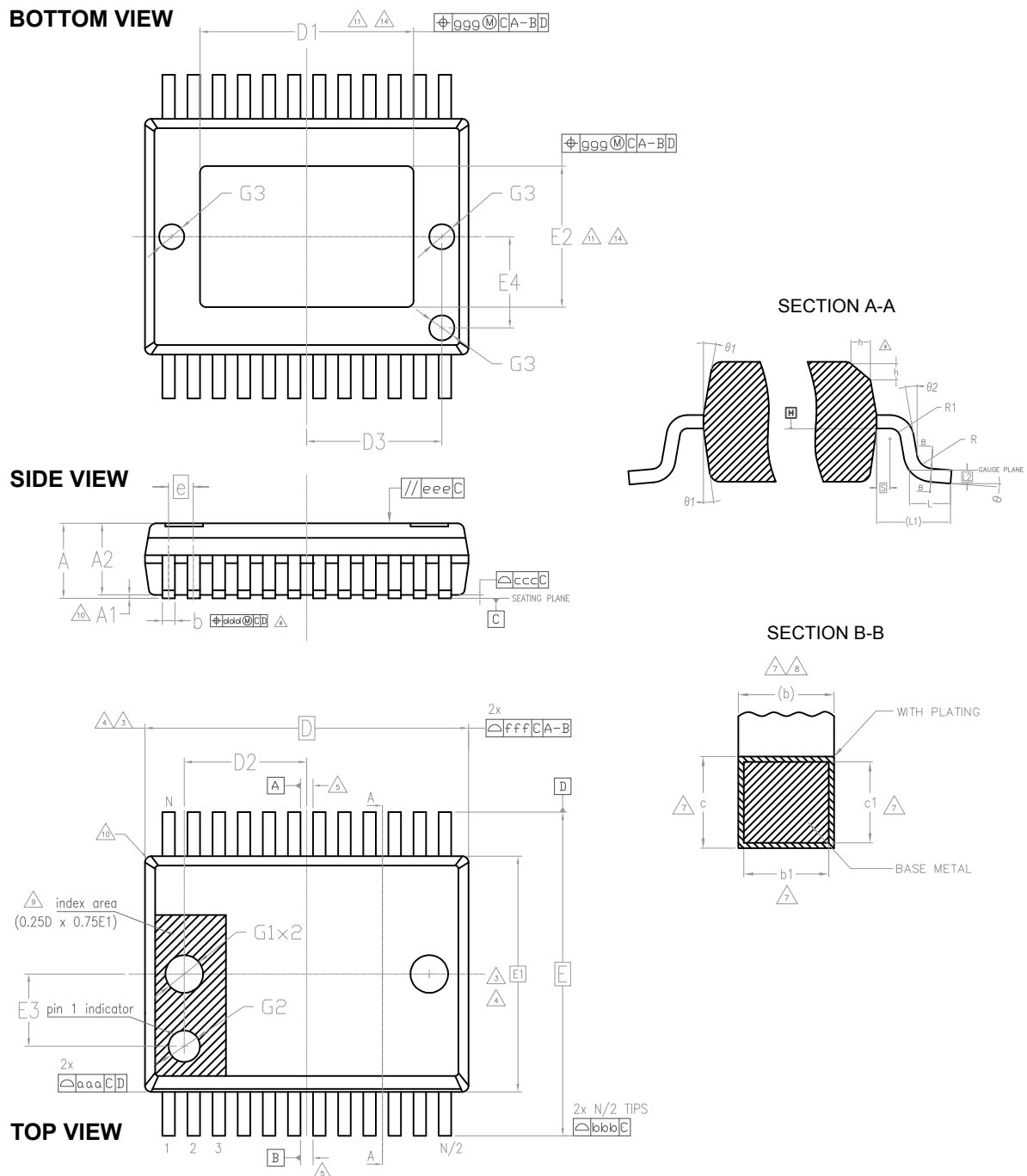
| Area / island (cm <sup>2</sup> ) | Footprint | 2  | 8  |
|----------------------------------|-----------|----|----|
| R1 = R7 (°C/W)                   | 0.6       |    |    |
| R2 = R8 (°C/W)                   | 0.75      |    |    |
| R3 (°C/W)                        | 1         |    |    |
| R4 (°C/W)                        | 7.7       |    |    |
| R5 (°C/W)                        | 9         | 9  | 8  |
| R6 (°C/W)                        | 28        | 17 | 10 |
| C1 = C7 (W.s/°C)                 | 0.005     |    |    |
| C2 = C8 (W.s/°C)                 | 0.01      |    |    |
| C3 (W.s/°C)                      | 0.05      |    |    |
| C4 (W.s/°C)                      | 0.3       |    |    |
| C5 (W.s/°C)                      | 1         | 4  | 9  |
| C6 (W.s/°C)                      | 2.2       | 5  | 17 |

## 8 Package information

To meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 8.1 PowerSSO-24 package information

Figure 36. PowerSSO-24 package dimensions



7412818\_14

**Table 13. PowerSSO-24 mechanical data**

| Symbol     | Millimeters |      |      |
|------------|-------------|------|------|
|            | Min.        | Typ. | Max. |
| $\theta$   | 0°          |      | 8°   |
| $\theta_1$ | 5°          |      | 10°  |
| $\theta_2$ | 0°          |      |      |
| A          |             |      | 2.45 |
| A1         | 0.00        |      | 0.10 |
| A2         | 2.15        |      | 2.35 |
| b          | 0.33        |      | 0.51 |
| b1         | 0.28        | 0.40 | 0.48 |
| c          | 0.23        |      | 0.32 |
| c1         | 0.20        | 0.20 | 0.30 |
| D          | 10.30 BSC   |      |      |
| D1         | 6.50        |      | 7.10 |
| D2         |             | 3.65 |      |
| D3         |             | 4.30 |      |
| e          | 0.80 BSC    |      |      |
| E          | 10.30 BSC   |      |      |
| E1         | 7.50 BSC    |      |      |
| E2         | 4.10        |      | 4.70 |
| E3         |             | 2.30 |      |
| E4         |             | 2.90 |      |
| G1         |             | 1.20 |      |
| G2         |             | 1.00 |      |
| G3         |             | 0.80 |      |
| h          | 0.30        |      | 0.40 |
| L          | 0.55        | 0.70 | 0.85 |
| L1         | 1.40 REF    |      |      |
| L2         | 0.25 BSC    |      |      |
| N          | 24          |      |      |
| R          | 0.30        |      |      |
| R1         | 0.20        |      |      |
| S          | 0.25        |      |      |

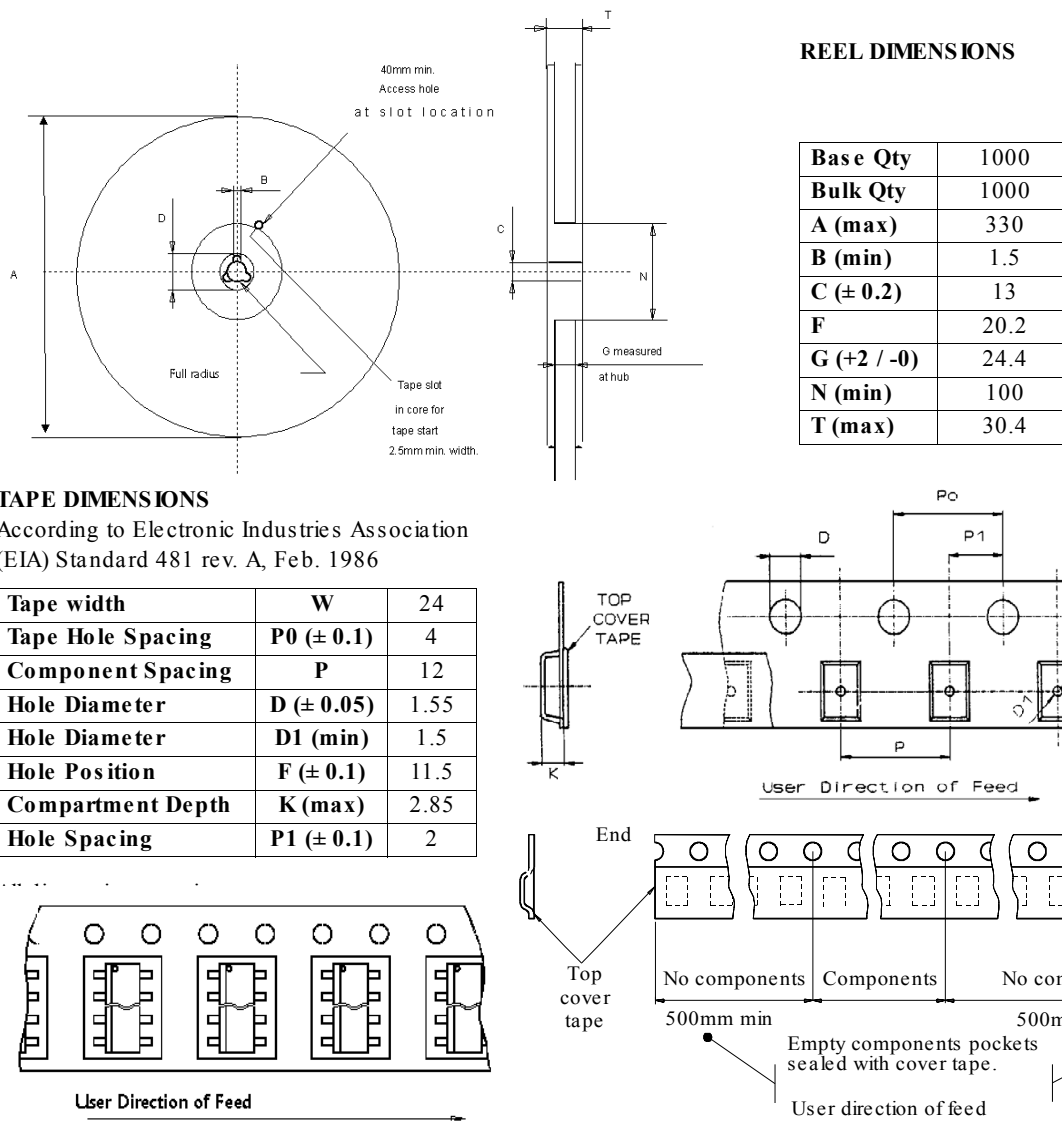
**Table 14. PowerSSO-24 tolerance of form and position**

| Symbol | Millimeters |
|--------|-------------|
| aaa    | 0.20        |
| bbb    | 0.20        |
| ccc    | 0.10        |
| ddd    | 0.20        |
| eee    | 0.10        |

| Symbol | Millimeters |
|--------|-------------|
| fff    | 0.20        |
| ggg    | 0.15        |

## 8.2 PowerSSO-24 packing information

**Figure 37. PowerSSO-24 tape and reel shipment**



## 9 Ordering information

**Table 15. Ordering information**

| Part number | Package     | Packing       |
|-------------|-------------|---------------|
| IPS2100THK  | PowerSSO-24 | Tape and reel |

## Revision history

**Table 16. Document revision history**

| Date        | Revision | Changes                                                          |
|-------------|----------|------------------------------------------------------------------|
| 27-Aug-2026 | 1        | Initial release.                                                 |
| 17-Sep-2026 | 2        | Changed Vcc AMR in <a href="#">Table 3</a> ; some minor changes. |

## Contents

|          |                                                     |           |
|----------|-----------------------------------------------------|-----------|
| <b>1</b> | <b>Block diagram and pin description</b>            | <b>2</b>  |
| <b>2</b> | <b>Electrical specification</b>                     | <b>4</b>  |
| 2.1      | Absolute maximum ratings                            | 4         |
| 2.2      | Thermal data                                        | 5         |
| 2.3      | Electrical characteristics                          | 6         |
| 2.4      | Electrical characteristics (curves)                 | 12        |
| <b>3</b> | <b>Protections</b>                                  | <b>14</b> |
| 3.1      | Thermal protections                                 | 14        |
| 3.1.1    | Current limitation                                  | 14        |
| 3.1.2    | Power limitation                                    | 14        |
| 3.1.3    | Thermal shutdown                                    | 15        |
| 3.2      | Negative voltage clamp                              | 15        |
| <b>4</b> | <b>Reset and standby mechanism description</b>      | <b>16</b> |
| <b>5</b> | <b>Active clamp</b>                                 | <b>18</b> |
| <b>6</b> | <b>Application information</b>                      | <b>19</b> |
| 6.1      | GND protection network against reverse polarity     | 19        |
| 6.1.1    | Solution 1: resistor in the ground line (RGND only) | 19        |
| 6.1.2    | Solution 2: diode (DGND) in the ground line         | 19        |
| 6.2      | Vcc overshoot protection                            | 19        |
| 6.3      | MCU I/Os protection                                 | 20        |
| 6.4      | Analog current sense                                | 20        |
| 6.4.1    | Principle of current sense signal generation        | 20        |
| 6.4.2    | Short to VCC and OFF-state open-load detection      | 21        |
| <b>7</b> | <b>Package and PCB thermal data</b>                 | <b>23</b> |
| 7.1      | PowerSSO-24 thermal data                            | 23        |
| <b>8</b> | <b>Package information</b>                          | <b>26</b> |
| 8.1      | PowerSSO-24 package information                     | 26        |
| 8.2      | PowerSSO-24 packing information                     | 29        |
| <b>9</b> | <b>Ordering information</b>                         | <b>30</b> |
|          | <b>Revision history</b>                             | <b>31</b> |
|          | <b>List of tables</b>                               | <b>33</b> |
|          | <b>List of figures</b>                              | <b>34</b> |

## List of tables

|                  |                                                                       |    |
|------------------|-----------------------------------------------------------------------|----|
| <b>Table 1.</b>  | Pin function . . . . .                                                | 3  |
| <b>Table 2.</b>  | Suggested connections for unused and not connected pins . . . . .     | 3  |
| <b>Table 3.</b>  | Absolute maximum ratings . . . . .                                    | 4  |
| <b>Table 4.</b>  | Thermal data . . . . .                                                | 5  |
| <b>Table 5.</b>  | Power section . . . . .                                               | 6  |
| <b>Table 6.</b>  | Switching ( $V_{CC} = 24\text{ V}$ , $T_J = 25\text{ °C}$ ) . . . . . | 6  |
| <b>Table 7.</b>  | Logic inputs . . . . .                                                | 6  |
| <b>Table 8.</b>  | Protections and diagnostics . . . . .                                 | 7  |
| <b>Table 9.</b>  | Current sense ( $8\text{ V} < V_{CC} < 36\text{ V}$ ) . . . . .       | 7  |
| <b>Table 10.</b> | Open-load detection ( $V_{FR\_STBY} = 5\text{ V}$ ) . . . . .         | 9  |
| <b>Table 11.</b> | Functional table . . . . .                                            | 17 |
| <b>Table 12.</b> | Thermal parameters . . . . .                                          | 25 |
| <b>Table 13.</b> | PowerSSO-24 mechanical data . . . . .                                 | 27 |
| <b>Table 14.</b> | PowerSSO-24 tolerance of form and position . . . . .                  | 27 |
| <b>Table 15.</b> | Ordering information . . . . .                                        | 30 |
| <b>Table 16.</b> | Document revision history . . . . .                                   | 31 |

## List of figures

|            |                                                                                                                                     |    |
|------------|-------------------------------------------------------------------------------------------------------------------------------------|----|
| Figure 1.  | Block diagram . . . . .                                                                                                             | 2  |
| Figure 2.  | Configuration diagram PowerSSO-24 (top view) . . . . .                                                                              | 3  |
| Figure 3.  | Current and voltage conventions . . . . .                                                                                           | 4  |
| Figure 4.  | Current sense delay characteristics . . . . .                                                                                       | 9  |
| Figure 5.  | Switching characteristics . . . . .                                                                                                 | 9  |
| Figure 6.  | Output stuck to $V_{CC}$ detection delay time at FR_STBY activation . . . . .                                                       | 10 |
| Figure 7.  | Delay response time between rising edge of output current and rising edge of current sense for each channel (CSx enabled) . . . . . | 10 |
| Figure 8.  | Output voltage drop limitation . . . . .                                                                                            | 11 |
| Figure 9.  | Off-state output current . . . . .                                                                                                  | 12 |
| Figure 10. | High level input current . . . . .                                                                                                  | 12 |
| Figure 11. | Input clamp voltage . . . . .                                                                                                       | 12 |
| Figure 12. | Low level input voltage . . . . .                                                                                                   | 12 |
| Figure 13. | High level input voltage . . . . .                                                                                                  | 12 |
| Figure 14. | Input hysteresis voltage . . . . .                                                                                                  | 12 |
| Figure 15. | On-state resistance vs $T_C$ . . . . .                                                                                              | 13 |
| Figure 16. | On-state resistance vs $V_{CC}$ . . . . .                                                                                           | 13 |
| Figure 17. | Turn-on voltage slope . . . . .                                                                                                     | 13 |
| Figure 18. | Turn-off voltage slope . . . . .                                                                                                    | 13 |
| Figure 19. | $I_{limH}$ vs $T_C$ . . . . .                                                                                                       | 13 |
| Figure 20. | Power limitation on a shorted load (FR_STBY = Low) . . . . .                                                                        | 14 |
| Figure 21. | Power limitation with latch (FR_STBY = High). . . . .                                                                               | 15 |
| Figure 22. | Thermal shutdown response (no power limitation) (FR_STBY = Low) . . . . .                                                           | 15 |
| Figure 23. | $t_{reset}$ definition . . . . .                                                                                                    | 16 |
| Figure 24. | $t_{stby}$ definition . . . . .                                                                                                     | 16 |
| Figure 25. | Device behavior in overload condition . . . . .                                                                                     | 17 |
| Figure 26. | Active clamp typical waveforms . . . . .                                                                                            | 18 |
| Figure 27. | Maximum turn off current versus inductance . . . . .                                                                                | 18 |
| Figure 28. | Application schematic . . . . .                                                                                                     | 19 |
| Figure 29. | Current sense block diagram . . . . .                                                                                               | 20 |
| Figure 30. | Application schematic for open-load detection in off-state . . . . .                                                                | 22 |
| Figure 31. | Open-load / short to $V_{CC}$ condition . . . . .                                                                                   | 22 |
| Figure 32. | PowerSSO-24 PCB . . . . .                                                                                                           | 23 |
| Figure 33. | $R_{thJA}$ vs PCB copper area in open box free air condition (one channel ON) . . . . .                                             | 23 |
| Figure 34. | PowerSSO-24 thermal impedance junction ambient single pulse (one channel ON) . . . . .                                              | 24 |
| Figure 35. | Thermal fitting model of a quad channel HSD in PowerSSO-24 . . . . .                                                                | 24 |
| Figure 36. | PowerSSO-24 package dimensions . . . . .                                                                                            | 26 |
| Figure 37. | PowerSSO-24 tape and reel shipment . . . . .                                                                                        | 29 |

## ■ Disclaimer

### IMPORTANT NOTICE – READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice.

In the event of any conflict between the provisions of this document and the provisions of any contractual arrangement in force between the purchasers and ST, the provisions of such contractual arrangement shall prevail.

The purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgment.

The purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of the purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

If the purchasers identify an ST product that meets their functional and performance requirements but that is not designated for the purchasers' market segment, the purchasers shall contact ST for more information.

ST and the ST logo are trademarks of ST. For additional information about ST trademarks, refer to [www.st.com/trademarks](http://www.st.com/trademarks). All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2026 STMicroelectronics – All rights reserved